

Welcome to **E-XFL.COM**

Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Obsolete
Core Processor	MPC8xx
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	50MHz
Co-Processors/DSP	Communications; CPM
RAM Controllers	DRAM
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10Mbps (1)
SATA	-
USB	USB 1.x (1)
Voltage - I/O	3.3V
Operating Temperature	0°C ~ 95°C (TA)
Security Features	-
Package / Case	256-BBGA
Supplier Device Package	256-PBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mpc850srzq50bu

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



2 Features

Figure 1 is a block diagram of the MPC850, showing its major components and the relationships among those components:

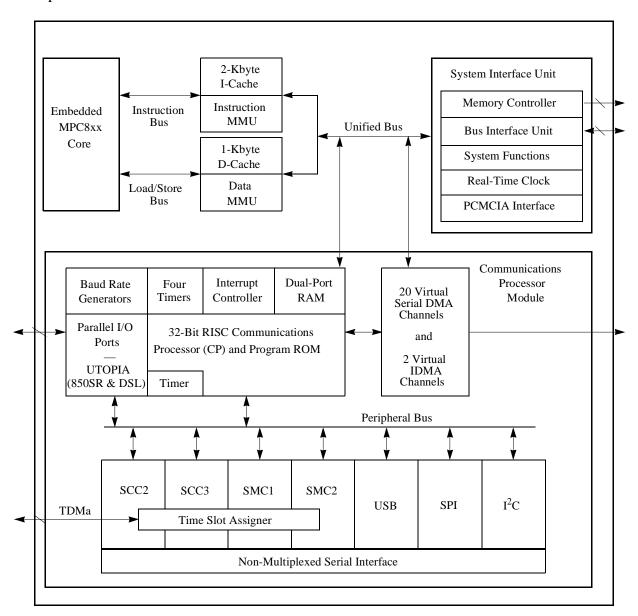


Figure 1. MPC850 Microprocessor Block Diagram

The following list summarizes the main features of the MPC850:

- Embedded single-issue, 32-bit MPC8xx core (implementing the PowerPC architecture) with thirty-two 32-bit general-purpose registers (GPRs)
 - Performs branch folding and branch prediction with conditional prefetch, but without conditional execution

MPC850 PowerQUICC™ Integrated Communications Processor Hardware Specifications, Rev. 2



- Separate power supply input to operate internal logic at 2.2 V when operating at or below 25 MHz
- Can be dynamically shifted between high frequency (3.3 V internal) and low frequency (2.2 V internal) operation
- Debug interface
 - Eight comparators: four operate on instruction address, two operate on data address, and two operate on data
 - The MPC850 can compare using the =, \neq , <, and > conditions to generate watchpoints
 - Each watchpoint can generate a breakpoint internally
- 3.3-V operation with 5-V TTL compatibility on all general purpose I/O pins.

3 Electrical and Thermal Characteristics

This section provides the AC and DC electrical specifications and thermal characteristics for the MPC850. Table 2 provides the maximum ratings.

Table 2. Maximum Ratings

(GND = 0V)

Rating	Symbol	Value	Unit
Supply voltage	VDDH	-0.3 to 4.0	V
	VDDL	-0.3 to 4.0	V
	KAPWR	-0.3 to 4.0	V
	VDDSYN	-0.3 to 4.0	V
Input voltage ¹	V _{in}	GND-0.3 to VDDH + 2.5 V	V
Junction temperature ²	Тј	0 to 95 (standard) -40 to 95 (extended)	°C
Storage temperature range	T _{stg}	-55 to +150	°C

Functional operating conditions are provided with the DC electrical specifications in Table 5. Absolute maximum ratings are stress ratings only; functional operation at the maxima is not guaranteed. Stress beyond those listed may affect device reliability or cause permanent damage to the device.

CAUTION: All inputs that tolerate 5 V cannot be more than 2.5 V greater than the supply voltage. This restriction

This device contains circuitry protecting against damage due to high-static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for example, either GND or V_{CC}). Table 3 provides the package thermal characteristics for the MPC850.

MPC850 PowerQUICC™ Integrated Communications Processor Hardware Specifications, Rev. 2

applies to power-up and normal operation (that is, if the MPC850 is unpowered, voltage greater than 2.5 V must not be applied to its inputs).

The MPC850, a high-frequency device in a BGA package, does not provide a guaranteed maximum ambient temperature. Only maximum junction temperature is guaranteed. It is the responsibility of the user to consider power dissipation and thermal management. Junction temperature ratings are the same regardless of frequency rating of the device.



 θ_{1A} = Package thermal resistance, junction to ambient, °C/W

$$P_D = P_{INT} + P_{I/O}$$

$$P_{INT} = I_{DD} \times V_{DD}$$
, watts—chip internal power

P_{I/O} = Power dissipation on input and output pins—user determined

For most applications $P_{I/O} < 0.3 \bullet P_{INT}$ and can be neglected. If $P_{I/O}$ is neglected, an approximate relationship between P_D and T_I is:

$$P_D = K \div (T_1 + 273^{\circ}C)(2)$$

Solving equations (1) and (2) for K gives:

$$K = P_D \cdot (T_A + 273^{\circ}C) + \theta_{JA} \cdot P_D^2(3)$$

where K is a constant pertaining to the particular part. K can be determined from equation (3) by measuring P_D (at equilibrium) for a known T_A . Using this value of K, the values of P_D and P_D and P_D can be obtained by solving equations (1) and (2) iteratively for any value of P_D .

5.1 Layout Practices

Each V_{CC} pin on the MPC850 should be provided with a low-impedance path to the board's supply. Each GND pin should likewise be provided with a low-impedance path to ground. The power supply pins drive distinct groups of logic on chip. The V_{CC} power supply should be bypassed to ground using at least four 0.1 μ F by-pass capacitors located as close as possible to the four sides of the package. The capacitor leads and associated printed circuit traces connecting to chip V_{CC} and GND should be kept to less than half an inch per capacitor lead. A four-layer board is recommended, employing two inner layers as V_{CC} and GND planes.

All output pins on the MPC850 have fast rise and fall times. Printed circuit (PC) trace interconnection length should be minimized in order to minimize undershoot and reflections caused by these fast output switching times. This recommendation particularly applies to the address and data busses. Maximum PC trace lengths of six inches are recommended. Capacitance calculations should consider all device loads as well as parasitic capacitances due to the PC traces. Attention to proper PCB layout and bypassing becomes especially critical in systems with higher capacitive loads because these loads create higher transient currents in the $V_{\rm CC}$ and GND circuits. Pull up all unused inputs or signals that will be inputs during reset. Special care should be taken to minimize the noise levels on the PLL supply pins.

6 Bus Signal Timing

Table 6 provides the bus operation timing for the MPC850 at 50 MHz, 66 MHz, and 80 MHz. Timing information for other bus speeds can be interpolated by equation using the MPC850 Electrical Specifications Spreadsheet found at http://www.mot.com/netcomm.

The maximum bus speed supported by the MPC850 is 50 MHz. Higher-speed parts must be operated in half-speed bus mode (for example, an MPC850 used at 66 MHz must be configured for a 33 MHz bus).

The timing for the MPC850 bus shown assumes a 50-pF load. This timing can be derated by 1 ns per 10 pF. Derating calculations can also be performed using the MPC850 Electrical Specifications Spreadsheet.

MPC850 PowerQUICC™ Integrated Communications Processor Hardware Specifications, Rev. 2



Table 6. Bus Operation Timing ¹ (continued)

Num	Chavastavistis	50 I	ИНz	66 I	ИНz	80 1	ИНz	FEACT	Cap Load	l lmit
Num	Characteristic	Min	Max	Min	Max	Min	Max	FFACT	(default 50 pF)	Unit
B28c	CLKOUT falling edge to WE[0-3] negated GPCM write access TRLX = 0,1 CSNT = 1 write access TRLX = 0, CSNT = 1, EBDF = 1	7.00	14.00	11.00	18.00	9.00	16.00	0.375	50.00	ns
B28d	CLKOUT falling edge to CS negated GPCM write access TRLX = 0,1 CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1	_	14.00	_	18.00	_	16.00	0.375	50.00	ns
B29	WE[0-3] negated to D[0-31], DP[0-3] high-Z GPCM write access, CSNT = 0	3.00	_	6.00	_	4.00	_	0.250	50.00	ns
B29a	WE[0-3] negated to D[0-31], DP[0-3] high-Z GPCM write access, TRLX = 0 CSNT = 1, EBDF = 0	8.00	_	13.00	_	11.00	_	0.500	50.00	ns
B29b	CS negated to D[0-31], DP[0-3], high-Z GPCM write access, ACS = 00, TRLX = 0 & CSNT = 0	3.00	_	6.00	_	4.00	_	0.250	50.00	ns
B29c	CS negated to D[0-31], DP[0-3] high-Z GPCM write access, TRLX = 0, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 0	8.00	_	13.00	_	11.00	_	0.500	50.00	ns
B29d	WE[0-3] negated to D[0-31], DP[0-3] high-Z GPCM write access, TRLX = 1, CSNT = 1, EBDF = 0	28.00	_	43.00	_	36.00	_	1.500	50.00	ns
B29e	CS negated to D[0-31], DP[0-3] high-Z GPCM write access, TRLX = 1, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 0	28.00	_	43.00	_	36.00	_	1.500	50.00	ns
B29f	WE[0-3] negated to D[0-31], DP[0-3] high-Z GPCM write access TRLX = 0, CSNT = 1, EBDF = 1	5.00	_	9.00	_	7.00	_	0.375	50.00	ns
B29g	CS negated to D[0–31], DP[0–3] high-Z GPCM write access TRLX = 0, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1	5.00	_	9.00	_	7.00	_	0.375	50.00	ns



Table 6. Bus Operation Timing ¹ (continued)

NI	Oh ava ataviatia	50 I	MHz	66 1	ИHz	80 1	ИHz	EEA OT	Cap Load	11!4
Num	Characteristic	Min	Max	Min	Max	Min	Max	FFACT	(default 50 pF)	Unit
B31	CLKOUT falling edge to CS valid - as requested by control bit CST4 in the corresponding word in the UPM	1.50	6.00	1.50	6.00	1.50	6.00	_	50.00	ns
B31a	CLKOUT falling edge to $\overline{\text{CS}}$ valid - as requested by control bit CST1 in the corresponding word in the UPM	5.00	12.00	8.00	14.00	6.00	13.00	0.250	50.00	ns
B31b	CLKOUT rising edge to CS valid - as requested by control bit CST2 in the corresponding word in the UPM	1.50	8.00	1.50	8.00	1.50	8.00	_	50.00	ns
B31c	CLKOUT rising edge to CS valid - as requested by control bit CST3 in the corresponding word in the UPM	5.00	12.00	8.00	14.00	6.00	13.00	0.250	50.00	ns
B31d	CLKOUT falling edge to CS valid - as requested by control bit CST1 in the corresponding word in the UPM EBDF = 1	9.00	14.00	13.00	18.00	11.00	16.00	0.375	50.00	ns
B32	CLKOUT falling edge to BS valid - as requested by control bit BST4 in the corresponding word in the UPM	1.50	6.00	1.50	6.00	1.50	6.00	_	50.00	ns
B32a	CLKOUT falling edge to BS valid - as requested by control bit BST1 in the corresponding word in the UPM, EBDF = 0	5.00	12.00	8.00	14.00	6.00	13.00	0.250	50.00	ns
B32b	CLKOUT rising edge to BS valid - as requested by control bit BST2 in the corresponding word in the UPM	1.50	8.00	1.50	8.00	1.50	8.00	_	50.00	ns
B32c	CLKOUT rising edge to BS valid - as requested by control bit BST3 in the corresponding word in the UPM	5.00	12.00	8.00	14.00	6.00	13.00	0.250	50.00	ns
B32d	CLKOUT falling edge to BS valid - as requested by control bit BST1 in the corresponding word in the UPM, EBDF = 1	9.00	14.00	13.00	18.00	11.00	16.00	0.375	50.00	ns
B33	CLKOUT falling edge to GPL valid - as requested by control bit GxT4 in the corresponding word in the UPM	1.50	6.00	1.50	6.00	1.50	6.00	_	50.00	ns

MPC850 PowerQUICC™ Integrated Communications Processor Hardware Specifications, Rev. 2



Table 6. Bus Operation Timing ¹ (continued)

Nivee	Characteristic	50 I	ИНz	66 N	ИHz	80 1	MHz	EEAOT	Cap Load	المثادا
Num	Characteristic	Min	Max	Min	Max	Min	Max	FFACT	(default 50 pF)	Unit
B33a	CLKOUT rising edge to GPL valid - as requested by control bit GxT3 in the corresponding word in the UPM	5.00	12.00	8.00	14.00	6.00	13.00	0.250	50.00	ns
B34	A[6–31] and D[0–31] to $\overline{\text{CS}}$ valid - as requested by control bit CST4 in the corresponding word in the UPM	3.00	_	6.00	_	4.00	_	0.250	50.00	ns
B34a	A[6–31] and D[0–31] to $\overline{\text{CS}}$ valid - as requested by control bit CST1 in the corresponding word in the UPM	8.00	_	13.00	_	11.00	_	0.500	50.00	ns
B34b	A[6–31] and D[0–31] to $\overline{\text{CS}}$ valid - as requested by CST2 in the corresponding word in UPM	13.00	_	21.00	_	17.00	_	0.750	50.00	ns
B35	A[6–31] to CS valid - as requested by control bit BST4 in the corresponding word in UPM	3.00	_	6.00	_	4.00	_	0.250	50.00	ns
B35a	A[6–31] and D[0–31] to \overline{BS} valid - as requested by BST1 in the corresponding word in the UPM	8.00	_	13.00	_	11.00	_	0.500	50.00	ns
B35b	A[6–31] and D[0–31] to BS valid - as requested by control bit BST2 in the corresponding word in the UPM	13.00	_	21.00	_	17.00	_	0.750	50.00	ns
B36	A[6–31] and D[0–31] to GPL valid - as requested by control bit GxT4 in the corresponding word in the UPM	3.00	_	6.00	_	4.00	_	0.250	50.00	ns
B37	UPWAIT valid to CLKOUT falling edge 10	6.00	_	6.00	_	6.00	_	_	50.00	ns
B38	CLKOUT falling edge to UPWAIT valid ¹⁰	1.00	_	1.00	_	1.00	_	_	50.00	ns
B39	AS valid to CLKOUT rising edge	7.00	_	7.00	_	7.00	_	_	50.00	ns
B40	A[6–31], TSIZ[0–1], RD/WR, BURST, valid to CLKOUT rising edge.	7.00	_	7.00	_	7.00	_	_	50.00	ns
B41	TS valid to CLKOUT rising edge (setup time)	7.00	_	7.00	_	7.00	_	_	50.00	ns



Figure 4 provides the timing for the synchronous output signals.

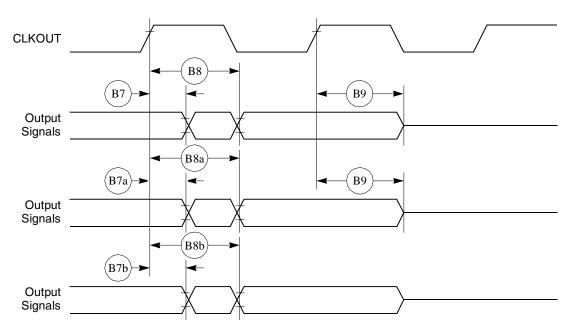


Figure 4. Synchronous Output Signals Timing

Figure 5 provides the timing for the synchronous active pull-up and open-drain output signals.

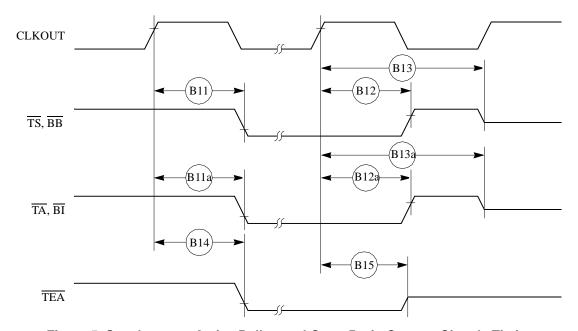


Figure 5. Synchronous Active Pullup and Open-Drain Outputs Signals Timing

MPC850 PowerQUICC™ Integrated Communications Processor Hardware Specifications, Rev. 2



Figure 16 provides the timing for the external bus controlled by the UPM.

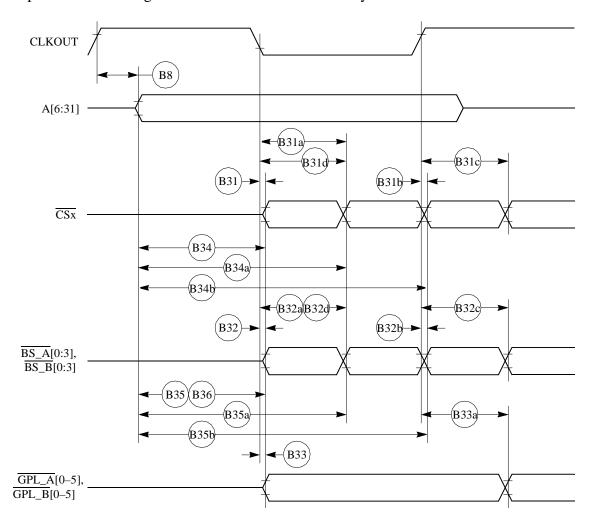


Figure 16. External Bus Timing (UPM Controlled Signals)



Figure 19 provides the timing for the synchronous external master access controlled by the GPCM.

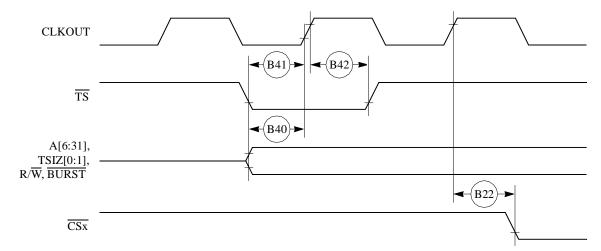


Figure 19. Synchronous External Master Access Timing (GPCM Handled ACS = 00)

Figure 20 provides the timing for the asynchronous external master memory access controlled by the GPCM.

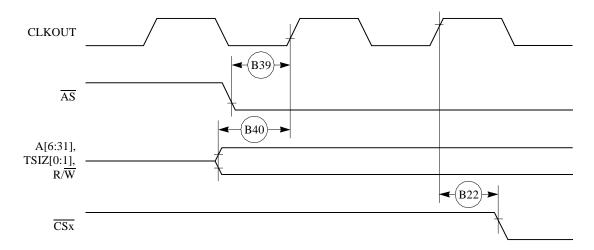


Figure 20. Asynchronous External Master Memory Access Timing (GPCM Controlled—ACS = 00)

Figure 21 provides the timing for the asynchronous external master control signals negation.

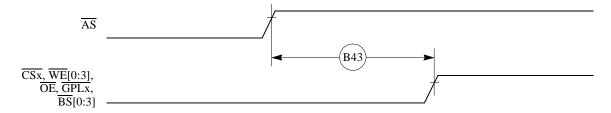


Figure 21. Asynchronous External Master—Control Signals Negation Timing

MPC850 PowerQUICC™ Integrated Communications Processor Hardware Specifications, Rev. 2



Table 7 provides interrupt timing for the MPC850.

Table 7. Interrupt Timing

Num	Characteristic ¹	50 MHz		66MHz		80 MHz		Unit
Num	Citalacteristic	Min	Max	Min	Max	Min	Max	
139	IRQx valid to CLKOUT rising edge (set up time)	6.00	_	6.00	_	6.00	_	ns
140	IRQx hold time after CLKOUT.	2.00	_	2.00	_	2.00	_	ns
141	IRQx pulse width low	3.00	_	3.00	_	3.00	_	ns
142	IRQx pulse width high	3.00	_	3.00	_	3.00	_	ns
143	IRQx edge-to-edge time	80.00	_	121.0	_	100.0	_	ns

The timings I39 and I40 describe the testing conditions under which the IRQ lines are tested when being defined as level sensitive. The IRQ lines are synchronized internally and do not have to be asserted or negated with reference to the CLKOUT.

Figure 22 provides the interrupt detection timing for the external level-sensitive lines.

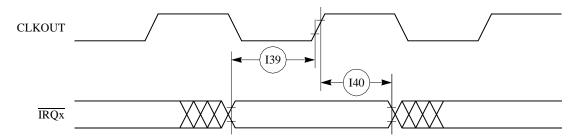


Figure 22. Interrupt Detection Timing for External Level Sensitive Lines

Figure 23 provides the interrupt detection timing for the external edge-sensitive lines.

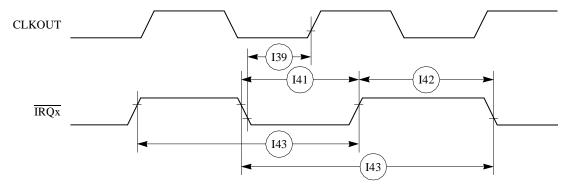


Figure 23. Interrupt Detection Timing for External Edge Sensitive Lines

The timings I41, I42, and I43 are specified to allow the correct function of the \overline{IRQ} lines detection circuitry, and has no direct relation with the total system interrupt latency that the MPC850 is able to support



Table 10 shows the debug port timing for the MPC850.

Table 10. Debug Port Timing

Num	Characteristic	50 MHz		66 MHz		80 MHz		Unit
Num	Characteristic	Min	Max	Min	Max	Min	Max	Oilit
D61	DSCK cycle time	60.00	_	91.00	_	75.00	_	ns
D62	DSCK clock pulse width	25.00	_	38.00	_	31.00	_	ns
D63	DSCK rise and fall times	0.00	3.00	0.00	3.00	0.00	3.00	ns
D64	DSDI input data setup time	8.00	_	8.00	_	8.00	_	ns
D65	DSDI data hold time	5.00	_	5.00	_	5.00	_	ns
D66	DSCK low to DSDO data valid	0.00	15.00	0.00	15.00	0.00	15.00	ns
D67	DSCK low to DSDO invalid	0.00	2.00	0.00	2.00	0.00	2.00	ns

Figure 29 provides the input timing for the debug port clock.

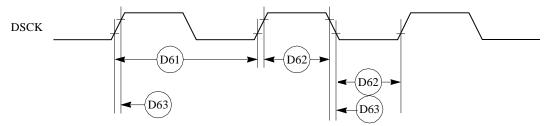


Figure 29. Debug Port Clock Input Timing

Figure 30 provides the timing for the debug port.

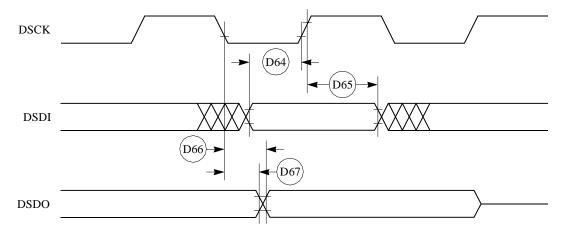


Figure 30. Debug Port Timings

MPC850 PowerQUICC™ Integrated Communications Processor Hardware Specifications, Rev. 2



Table 11 shows the reset timing for the MPC850.

Table 11. Reset Timing

Num	Characteristic	50 N	ЛНz	66N	ЛHz	80 1	ИНz	FFACTOR	Unit
INUIII	Characteristic	Min	Max	Min	Max	Min	Max	FFACION	Onit
R69	CLKOUT to HRESET high impedance	_	20.00	_	20.00	_	20.00	_	ns
R70	CLKOUT to SRESET high impedance	_	20.00	_	20.00	_	20.00	_	ns
R71	RSTCONF pulse width	340.00	_	515.00	_	425.00	_	17.000	ns
R72		_	_	_	_	_	_	_	
R73	Configuration data to HRESET rising edge set up time	350.00	_	505.00	_	425.00	_	15.000	ns
R74	Configuration data to RSTCONF rising edge set up time	350.00	_	350.00	_	350.00	_	_	ns
R75	Configuration data hold time after RSTCONF negation	0.00	_	0.00	_	0.00	_	_	ns
R76	Configuration data hold time after HRESET negation	0.00	_	0.00	_	0.00	_	_	ns
R77	HRESET and RSTCONF asserted to data out drive	_	25.00	_	25.00	_	25.00	_	ns
R78	RSTCONF negated to data out high impedance.	_	25.00	_	25.00	_	25.00	_	ns
R79	CLKOUT of last rising edge before chip tristates HRESET to data out high impedance.	_	25.00	_	25.00	_	25.00	_	ns
R80	DSDI, DSCK set up	60.00	_	90.00	_	75.00	_	3.000	ns
R81	DSDI, DSCK hold time	0.00	_	0.00	_	0.00	_	_	ns
R82	SRESET negated to CLKOUT rising edge for DSDI and DSCK sample	160.00	_	242.00	_	200.00	_	8.000	ns



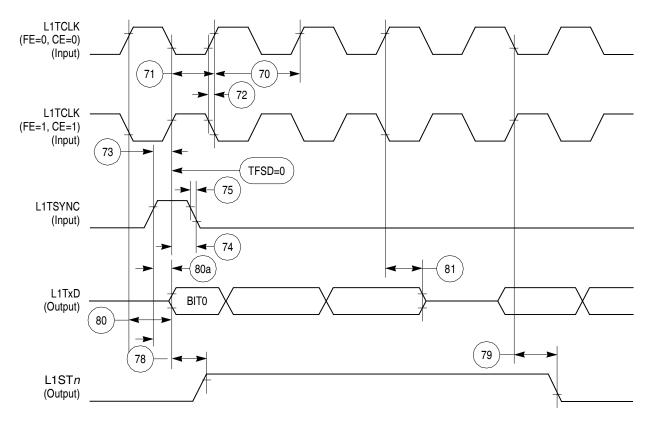


Figure 47. SI Transmit Timing Diagram



CPM Electrical Characteristics

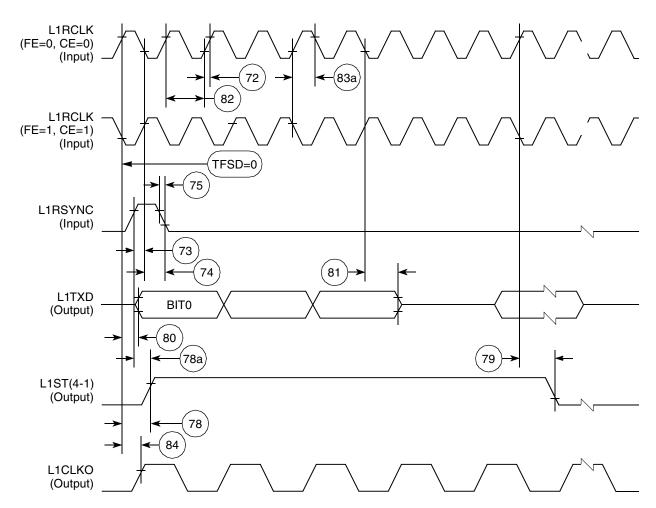


Figure 48. SI Transmit Timing with Double Speed Clocking (DSC = 1)



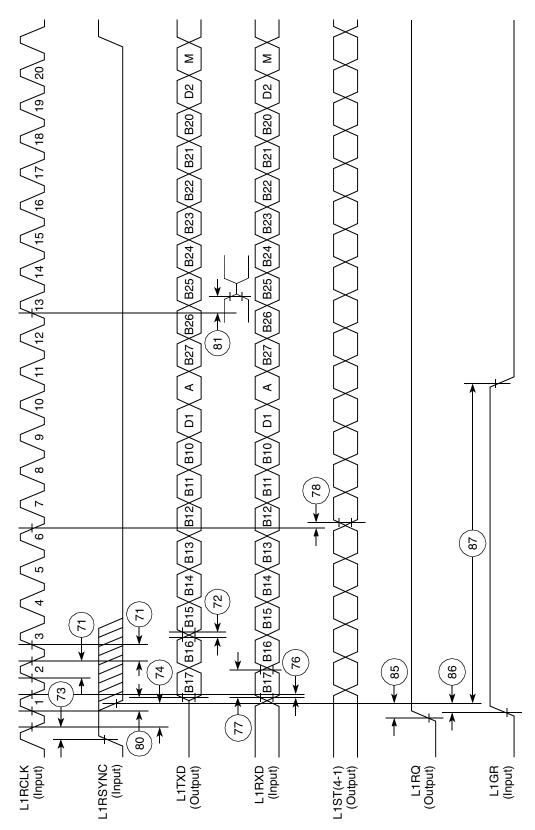


Figure 49. IDL Timing

MPC850 PowerQUICC™ Integrated Communications Processor Hardware Specifications, Rev. 2



8.10 SPI Slave AC Electrical Specifications

Table 23 provides the SPI slave timings as shown in Figure 59 and Figure 60.

Table 23. SPI Slave Timing

Num	Characteristic	All Frequ	uencies	Unit
Nulli	Characteristic	Min	Max	Oilit
170	Slave cycle time	2	_	t _{cyc}
171	Slave enable lead time	15.00	_	ns
172	Slave enable lag time	15.00	_	ns
173	Slave clock (SPICLK) high or low time	1	_	t _{cyc}
174	Slave sequential transfer delay (does not require deselect)	1	_	t _{cyc}
175	Slave data setup time (inputs)	20.00	_	ns
176	Slave data hold time (inputs)	20.00	_	ns
177	Slave access time	_	50.00	ns
178	Slave SPI MISO disable time	_	50.00	ns
179	Slave data valid (after SPICLK edge)	_	50.00	ns
180	Slave data hold time (outputs)	0.00	_	ns
181	Rise time (input)	_	15.00	ns
182	Fall time (input)	_	15.00	ns



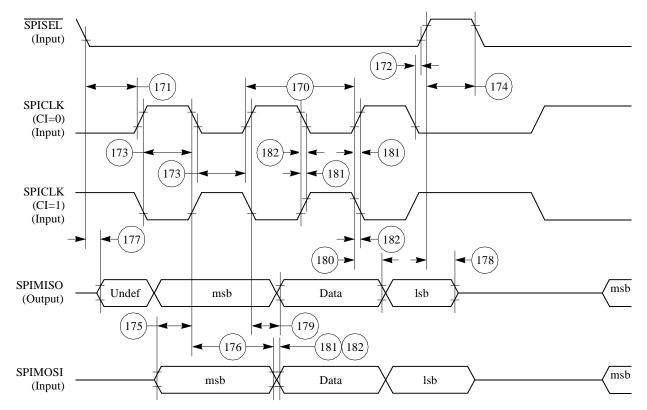


Figure 60. SPI Slave (CP = 1) Timing Diagram

8.11 I²C AC Electrical Specifications

Table 24 provides the I^2C (SCL < 100 KHz) timings.

Table 24. I²C Timing (SCL < 100 KHz)

Num	Characteristic	All Frequ	encies	Unit
Num	Characteristic	Min	Max	Ollit
200	SCL clock frequency (slave)	0.00	100.00	KHz
200	SCL clock frequency (master) ¹	1.50	100.00	KHz
202	Bus free time between transmissions	4.70	_	μs
203	Low period of SCL	4.70	_	μs
204	High period of SCL	4.00		μs
205	Start condition setup time	4.70	_	μs
206	Start condition hold time	4.00	_	μs
207	Data hold time	0.00	_	μs
208	Data setup time	250.00	_	ns
209	SDL/SCL rise time	_	1.00	μs

MPC850 PowerQUICC™ Integrated Communications Processor Hardware Specifications, Rev. 2



Table 24. I²C Timing (SCL < 100 KHz) (CONTINUED)

Num	Characteristic	All Frequ	Unit	
INGIII	Onaracteristic	Min	Max	Ome
210	SDL/SCL fall time	_	300.00	ns
211	Stop condition setup time	4.70	_	μs

SCL frequency is given by SCL = BRGCLK_frequency / ((BRG register + 3) * pre_scaler * 2). The ratio SyncClk/(BRGCLK/pre_scaler) must be greater or equal to 4/1.

Table 25 provides the I^2C (SCL > 100 KHz) timings.

Table 25. I^2C Timing (SCL > 100 KHz)

Num	Characteristic	Expression -	All Freq	uencies	Unit
Nulli	Characteristic	Expression	Min	Max	Onit
200	SCL clock frequency (slave)	fSCL	0	BRGCLK/48	Hz
200	SCL clock frequency (master) ¹	fSCL	BRGCLK/16512	BRGCLK/48	Hz
202	Bus free time between transmissions		1/(2.2 * fSCL)	_	S
203	Low period of SCL		1/(2.2 * fSCL)	_	S
204	High period of SCL		1/(2.2 * fSCL)	_	S
205	Start condition setup time		1/(2.2 * fSCL)	_	S
206	Start condition hold time		1/(2.2 * fSCL)	_	s
207	Data hold time		0	_	s
208	Data setup time		1/(40 * fSCL)	_	s
209	SDL/SCL rise time		_	1/(10 * fSCL)	S
210	SDL/SCL fall time		_	1/(33 * fSCL)	S
211	Stop condition setup time		1/2(2.2 * fSCL)	_	S

SCL frequency is given by SCL = BrgClk_frequency / ((BRG register + 3) * pre_scaler * 2). The ratio SyncClk/(Brg_Clk/pre_scaler) must be greater or equal to 4/1.

Figure 61 shows the I²C bus timing.

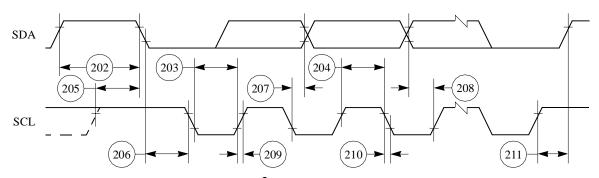


Figure 61. I²C Bus Timing Diagram

MPC850 PowerQUICC™ Integrated Communications Processor Hardware Specifications, Rev. 2



Mechanical Data and Ordering Information

customers that are currently using the non-JEDEC pin numbering scheme, two sets of pinouts, JEDEC and non-JEDEC, are presented in this document.

Figure 62 shows the non-JEDEC pinout of the PBGA package as viewed from the top surface.

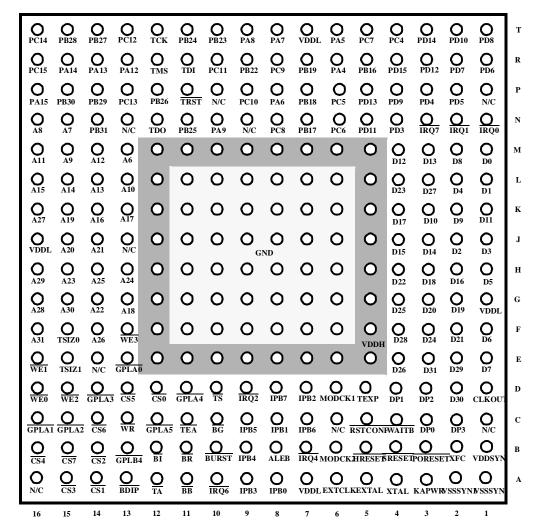


Figure 62. Pin Assignments for the PBGA (Top View)—non-JEDEC Standard

MPC850 PowerQUICC™ Integrated Communications Processor Hardware Specifications, Rev. 2



How to Reach Us:

Home Page:

www.freescale.com

email

support@freescale.com

USA/Europe or Locations Not Listed:

Freescale Semiconductor Technical Information Center, CH370 1300 N. Alma School Road Chandler, Arizona 85224 (800) 521-6274 480-768-2130 support@freescale.com

Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH Technical Information Center Schatzbogen 7 81829 Muenchen, Germany +44 1296 380 456 (English) +46 8 52200080 (English) +49 89 92103 559 (German) +33 1 69 35 48 48 (French) support@freescale.com

Japan:

Freescale Semiconductor Japan Ltd. Headquarters ARCO Tower 15F 1-8-1, Shimo-Meguro, Meguro-ku Tokyo 153-0064, Japan 0120 191014 +81 2666 8080 support.japan@freescale.com

Asia/Pacific:

Freescale Semiconductor Hong Kong Ltd. Technical Information Center 2 Dai King Street Tai Po Industrial Estate, Tai Po, N.T., Hong Kong +800 2666 8080 support.asia@freescale.com

For Literature Requests Only:

Freescale Semiconductor
Literature Distribution Center
P.O. Box 5405
Denver, Colorado 80217
(800) 441-2447
303-675-2140
Fax: 303-675-2150
LDCForFreescaleSemiconductor
@ hibbertgroup.com

implied copyright licenses granted hereunder to design or fabricate any integrated circuits or integrated circuits based on the information in this document.

Freescale Semiconductor reserves the right to make changes without further notice any products herein. Freescale Semiconductor makes no warranty, representation

implementers to use Freescale Semiconductor products. There are no express or

Information in this document is provided solely to enable system and software

Freescale Semiconductor reserves the right to make changes without further notice to any products herein. Freescale Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Freescale Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Freescale Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Freescale Semiconductor does not convey any license under its patent rights nor the rights of others. Freescale Semiconductor products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Freescale Semiconductor product could create a situation where personal injury or death may occur. Should Buyer purchase or use Freescale Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold Freescale Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Freescale Semiconductor was negligent regarding the design or manufacture of the part.

Freescale[™] and the Freescale logo are trademarks of Freescale Semiconductor, Inc. All other product or service names are the property of their respective owners.

© Freescale Semiconductor, Inc., 2005.

Document Number: MPC850EC

Rev. 2 07/2005

